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March 2016



FFA40UP35S 40 A, 350 V Ultrafast Diode

#### **Features**

- Ultrafast Recovery,  $t_{rr}$  < 55 ns (@  $I_F$  = 40 A)
- Max. Forward Voltage, V<sub>F</sub> =1.6 V(T<sub>c</sub> = 25°C)
- Reverse Voltage: V<sub>RRM</sub> = 350 V
- · Avalanche Energy Rated
- · RoHS Compliant

#### **Applications**

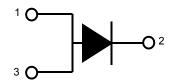
- · General Purpose
- · SMPS, Free-Wheeling Diode for Motor Application
- · Power Switching Circuits, Welder, UPS

#### Description

The FFA40UP35S is an ultrafast diode with low forward voltage drop and rugged UIS capability. This device is intended for use as freewheeling and clamping diodes in a variety of switching power supplies and other power swithching applications. It is specially suited for use in switching power supplies and industrial applicationa as welder and UPS application.







1. Anode 2. Cathode 3. Anode

### Absolute Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Unit	
$V_{RRM}$	Peak Repetitive Reverse Voltage	350	V	
$V_{RWM}$	Working Peak Reverse Voltage	350	V	
$V_R$	DC Blocking Voltage	350	V	
I <sub>F(AV)</sub>	Average Rectified Forward Current @ T <sub>C</sub> = 125°C	40	Α	
I <sub>FSM</sub>	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave	300	А	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range	-65 to +175	°C	

#### **Thermal Characteristics**

Symbol	Parameter	Ratings	Unit
$R_{\theta JC}$	Maximum Thermal Resistance, Junction to Case	0.8	°C/W

#### **Package Marking and Ordering Information**

Part N	umber	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FFA40U	P35STU	F40UP35S	TO-3P	Tube	N/A	N/A	30

## **Electrical Characteristics** $T_C = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Min.	Тур.	Max.	Unit	
V <sub>F</sub> 1	I <sub>F</sub> = 40 A I <sub>F</sub> = 40 A	$T_{\rm C} = 25^{\rm o}{\rm C}$ $T_{\rm C} = 125^{\rm o}{\rm C}$		-	1.6 1.5	V
I <sub>R</sub> 1	V <sub>R</sub> = 350 V V <sub>R</sub> = 350 V	$T_{\rm C} = 25^{\rm o}{\rm C}$ $T_{\rm C} = 125^{\rm o}{\rm C}$		-	100 500	μА
t <sub>rr</sub>	$I_F = 1 \text{ A, } di_F/dt = 100 \text{ A/}\mu\text{s, V}_R = 30 \text{ V}$ $I_F = 40 \text{ A, } di_F/dt = 200 \text{ A/}\mu\text{s, V}_R = 230 \text{ V}$	T <sub>C</sub> = 25°C		26 28	53 55	ns
t <sub>a</sub> t <sub>b</sub> Q <sub>rr</sub>	$I_F = 40 \text{ A}, \text{ di}_F/\text{dt} = 200 \text{ A/}\mu\text{s}, \text{ V}_R = 230 \text{V}$	T <sub>C</sub> = 25°C	-	17 11 36	-	ns ns nC
W <sub>AVL</sub>	Avalanche Energy ( L = 40 mH)	,	20	-	-	mJ

Notes: 1: Pulse: Test Pulse width =  $300\mu s$ , Duty Cycle = 2%

#### **Test Circuit and Waveforms**

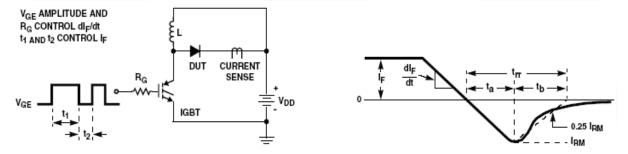


Figure 1. Diode Reverse Recovery Test Circuit & Waveform

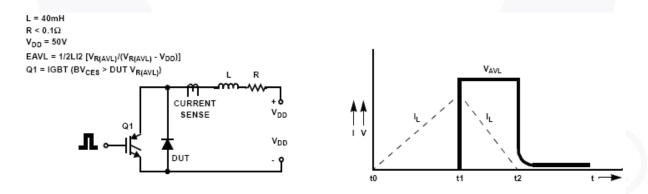


Figure 2. Unclamped Inductive Switching Test Circuit & Waveform

#### **Typical Performance Characteristics**

Figure 3. Typical Forward Voltage Drop vs. Forward Current

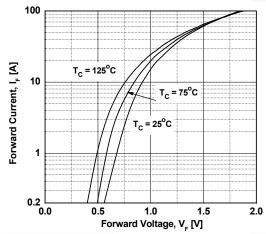


Figure 5. Typical Junction Capacitance

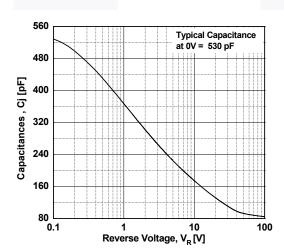


Figure 7. Typical Reverse Recovery Current vs. di<sub>F</sub>/dt

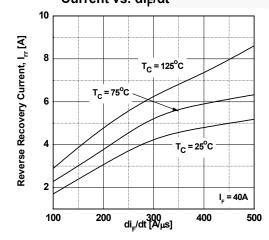


Figure 4. Typical Reverse Current vs.

Reverse Voltage

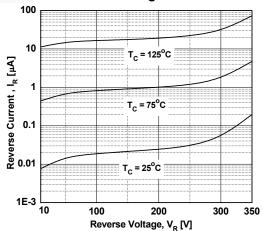


Figure 6. Typical Reverse Recovery Time vs. di<sub>F</sub>/dt

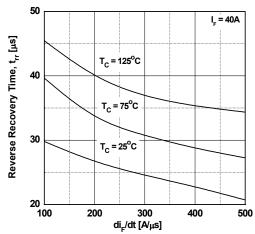
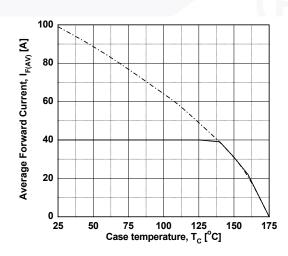
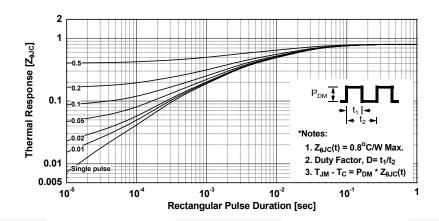


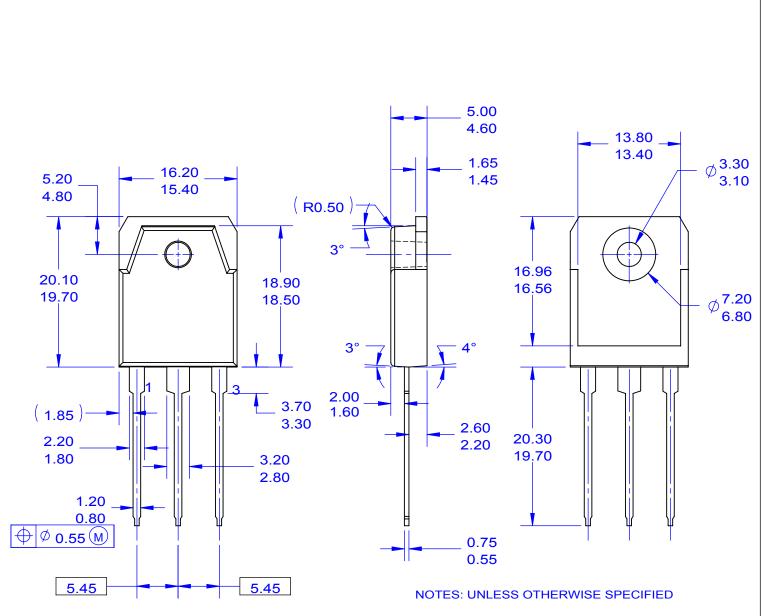
Figure 8. Forward Current Derating Curve

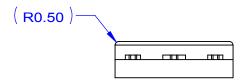


### **Typical Performance Characteristics** (Continued)

Figure 9. Transient Thermal Response Curve







- A) THIS PACKAGE CONFORMS TO EIAJ SC-65 PACKAGING STANDARD.
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSION AND TOLERANCING PER ASME14.5-2009.
- D) DIMENSIONS ARE EXCLUSSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSSIONS.
- E) DRAWING FILE NAME: TO3PN03AREV2.
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